## NSN 5961-01-036-6334

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**Fiig:** A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-036-6334 **Inclosure Material:** Metal **Overall Length:** Between 0.240 inches and 0.260 inches **Overall Diameter:** Between 0.305 inches and 0.335 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 300.0 breakdown voltage, collector-to-emitter, base open and 300.0 collector to base voltage/static/emitter open and 7.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No